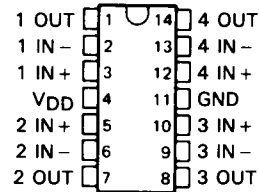


TLC274, TLC274A, TLC274B, TLC279 LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

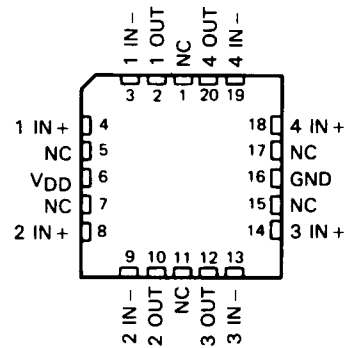
D3141, SEPTEMBER 1987—REVISED OCTOBER 1990

- **Trimmed Offset Voltage:**
TLC279 . . . 900 μV Max at 25°C,
VDD = 5 V
- **Input Offset Voltage Drift . . . Typically**
0.1 $\mu\text{V}/\text{Month}$, Including the First 30 Days
- **Wide Range of Supply Voltages Over**
Specified Temperature Range:
0°C to 70°C . . . 3 V to 16 V
-40°C to 85°C . . . 4 V to 16 V
-55°C to 125°C . . . 4 V to 16 V
- **Single-Supply Operation**
- **Common-Mode Input Voltage Range**
Extends Below the Negative Rail (C-Suffix,
I-Suffix types)
- **Low Noise . . . Typically 25 nV/ $\sqrt{\text{Hz}}$**
at $f = 1 \text{ kHz}$
- **Output Voltage Range Includes Negative**
Rail
- **High Input Impedance . . . $10^{12} \Omega$ Typical**
- **ESD-Protection Circuitry**
- **Small-Outline Package Option Also Available**
in Tape and Reel
- **Designed-In Latch-Up Immunity**

**D, J, OR N PACKAGE
(TOP VIEW)**



**FK PACKAGE
(TOP VIEW)**



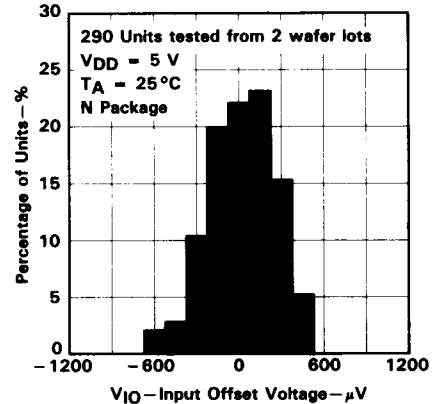
NC—No internal connection

AVAILABLE OPTIONS

TA	V _{IO} max at 25°C	PACKAGE			
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)
0°C to 70°C	900 μV	TLC279CD	—	—	TLC279CN
	2 mV	TLC274BCD	—	—	TLC274BCN
	5 mV	TLC274ACD	—	—	TLC274ACN
	10 mV	TLC274CD	—	—	TLC274CN
-40°C to 85°C	900 μV	TLC279ID	—	—	TLC279IN
	2 mV	TLC274BID	—	—	TLC274BIN
	5 mV	TLC274AID	—	—	TLC274AIN
	10 mV	TLC274ID	—	—	TLC274IN
-55°C to 125°C	900 μV	TLC279MD	TLC279MFK	TLC279MJ	TLC279MN
	10 mV	TLC274MD	TLC274MFK	TLC274MJ	TLC274MN

The D package is available in tape and reel. Add R suffix to the device type, (e.g., TLC279CDR).

**DISTRIBUTION OF TLC279
INPUT OFFSET VOLTAGE**



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INSTRUMENTS**

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TLC274, TLC274A, TLC274B, TLC279

LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

description

The TLC274 and TLC279 quad operational amplifiers combine a wide range of input offset voltage grades with low offset voltage drift, high input impedance, low noise, and speeds approaching that of general-purpose BiFET devices.

These devices use Texas Instruments silicon-gate LinCMOS™ technology, which provides offset voltage stability far exceeding the stability available with conventional metal-gate processes.

The extremely high input impedance, low bias currents, and high slew rates make these cost-effective devices ideal for applications which have previously been reserved for BiFET and NFET products. Four offset voltage grades are available (C-suffix and I-suffix types), ranging from the low-cost TLC274 (10 mV) to the high-precision TLC279 (900 μ V). These advantages, in combination with good common-mode rejection and supply voltage rejection, make these devices a good choice for new state-of-the-art designs as well as for upgrading existing designs.

In general, many features associated with bipolar technology are available on LinCMOS™ operational amplifiers, without the power penalties of bipolar technology. General applications such as transducer interfacing, analog calculations, amplifier blocks, active filters, and signal buffering are easily designed with the TLC274 and TLC279. The devices also exhibit low voltage single-supply operation, making them ideally suited for remote and inaccessible battery-powered applications. The common-mode input voltage range includes the negative rail.

A wide range of packaging options is available, including small-outline and chip carrier versions for high-density system applications.

The device inputs and outputs are designed to withstand -100 -mA surge currents without sustaining latch-up.

The TLC274 and TLC279 incorporate internal ESD-protection circuits that prevent functional failures at voltages up to 2000 V as tested under MIL-STD-883C, Method 3015.2; however, care should be exercised in handling these devices as exposure to ESD may result in the degradation of the device parametric performance.

C-suffix devices are characterized for operation from 0°C to 70°C. I-suffix devices are characterized for operation from -40 °C to 85°C. M-suffix devices are characterized for operation over the full military temperature range of -55 °C to 125°C.

TLC274, TLC274A, TLC274B, TLC279

LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{DD} (see Note 1)	18 V
Differential input voltage (see Note 2)	$\pm V_{DD}$
Input voltage range, V_I (any input)	-0.3 V to V_{DD}
Input current, I_I	± 5 mA
Output current, I_O (each output)	± 30 mA
Total current into V_{DD} terminal	45 mA
Total current out of ground terminal	45 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	Unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature, T_A : C-suffix	0°C to 70°C
I-suffix	-40°C to 85°C
M-suffix	-55°C to 125°C
Storage temperature range	-65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D and N package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package	300°C

- NOTES: 1. All voltage values, except differential voltages, are with respect to network ground.
 2. Differential voltages are at the noninverting input with respect to the inverting input.
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded (see application section).

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$	$T_A = 85^\circ\text{C}$	$T_A = 125^\circ\text{C}$
	POWER RATING		POWER RATING	POWER RATING	POWER RATING
D	950 mW	7.6 mW/°C	608 mW	494 mW	
FK	1375 mW	11 mW/°C	880 mW	715 mW	275 mW
J	1375 mW	11 mW/°C	880 mW	715 mW	275 mW
N	1575 mW	12.6 mW/°C	1008 mW	819 mW	

recommended operating conditions

		C-SUFFIX			I-SUFFIX			M-SUFFIX			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{DD}		3		16	4		16	4		16	V
Common-mode input voltage, V_{IC}	$V_{DD} = 5$ V	-0.2		3.5	-0.2		3.5	0		3.5	V
	$V_{DD} = 10$ V	-0.2		8.5	-0.2		8.5	0		8.5	
Operating free-air temperature, T_A		0		70	-40		85	-55		125	°C



TLC274M, TLC279M
LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A^\dagger	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	TLC274M	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	1.1	10	mV
					Full range		12	
		TLC279M	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	320	900	μV
					Full range		3750	
α_{VIO}	Average temperature coefficient of input offset voltage			25°C to 125°C		2.1		$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current (see Note 4)	$V_O = 2.5\text{ V}$	$V_{IC} = 2.5\text{ V}$	25°C		0.1		pA
				125°C		1.4	15	nA
I_{IB}	Input bias current (see Note 4)	$V_O = 2.5\text{ V}$	$V_{IC} = 2.5\text{ V}$	25°C		0.6		pA
				125°C		9	35	nA
V_{ICR}	Common-mode input voltage range (see Note 5)			25°C	0 to 4	-0.3 to 4.2		V
				Full range	0 to 3.5			V
V_{OH}	High-level output voltage	$V_{ID} = 100\text{ mV}$	$R_L = 10\text{ k}\Omega$	25°C	3.2	3.8		V
				-55°C	3	3.8		
				125°C	3	3.8		
V_{OL}	Low-level output voltage	$V_{ID} = -100\text{ mV}$	$I_{OL} = 0$	25°C		0	50	mV
				-55°C		0	50	
				125°C		0	50	
A_{VD}	Large-signal differential voltage amplification	$V_O = 0.25\text{ V to }2\text{ V}$	$R_L = 10\text{ k}\Omega$	25°C	5	23		V/mV
				-55°C	3.5	35		
				125°C	3.5	16		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR\text{ min}}$		25°C	65	80		dB
				-55°C	60	81		
				125°C	60	84		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to }10\text{ V}$	$V_O = 1.4\text{ V}$	25°C	65	95		dB
				-55°C	60	90		
				125°C	60	97		
I_{DD}	Supply current (four amplifiers)	$V_O = 2.5\text{ V}$, No load	$V_{IC} = 2.5\text{ V}$	25°C		2.7	6.4	mA
				-55°C		4	10	
				125°C		1.9	4.4	

† Full range is -55°C to 125°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.
5. This range also applies to each input individually.

TLC274M, TLC279M

LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

electrical characteristics at specified free-air temperature, $V_{DD} = 10\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A †	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	TLC274M	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	1.1	10	mV	
				Full range		12		
		TLC279M	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	370	1200	μV	
				Full range		4300		
α_{VIO}	Average temperature coefficient of input offset voltage			25°C to 125°C	2.2		$\mu\text{V}/^\circ\text{C}$	
I_{IO}	Input offset current (see Note 4)	$V_O = 5\text{ V}$, $V_{IC} = 5\text{ V}$		25°C	0.1		pA	
				125°C	1.8	15	nA	
I_{IB}	Input bias current (see Note 4)	$V_O = 5\text{ V}$, $V_{IC} = 5\text{ V}$		25°C	0.7		pA	
				125°C	10	35	nA	
V_{ICR}	Common-mode input voltage range (see Note 5)			25°C	0 to 9	-0.3 to 9.2	V	
				Full range	0 to 8.5		V	
V_{OH}	High-level output voltage	$V_{ID} = 100\text{ mV}$, $R_L = 10\text{ k}\Omega$		25°C	8	8.5	V	
				-55°C	7.8	8.5		
				125°C	7.8	8.4		
V_{OL}	Low-level output voltage	$V_{ID} = -100\text{ mV}$, $I_{OL} = 0$		25°C		0 to 50	mV	
				-55°C		0 to 50		
				125°C		0 to 50		
A_{VD}	Large-signal differential voltage amplification	$V_O = 1\text{ V to }6\text{ V}$, $R_L = 10\text{ k}\Omega$		25°C	10	36	V/mV	
				-55°C	7	50		
				125°C	7	27		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR\text{ min}}$		25°C	65	85	dB	
				-55°C	60	87		
				125°C	60	86		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to }10\text{ V}$, $V_O = 1.4\text{ V}$		25°C	65	95	dB	
				-55°C	60	90		
				125°C	60	97		
I_{DD}	Supply current (four amplifiers)	$V_O = 5\text{ V}$, No load	$V_{IC} = 5\text{ V}$	25°C	3.8	8	mA	
				-55°C	6.0	12		
				125°C	2.5	5.6		

† Full range is -55°C to 125°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.
5. This range also applies to each input individually.

TLC274I, TLC274AI, TLC274BI, TLC279I LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A^\dagger	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	TLC274I	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $R_L = 10\text{ k}\Omega$	$V_{IC} = 0$, 25°C		1.1	10	mV
				Full range			13	
		TLC274AI	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $R_L = 10\text{ k}\Omega$	25°C		0.9	5	mV
				Full range			7	
TLC274BI	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $R_L = 10\text{ k}\Omega$	25°C		340	2000	μV		
		Full range			3500			
TLC279I	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $R_L = 10\text{ k}\Omega$	$V_{IC} = 0$, 25°C		320	900	μV		
Full range				2000				
α_{VIO}	Average temperature coefficient of input offset voltage			25°C to 85°C		1.8		$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current (see Note 4)	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$		25°C		0.1		pA
				85°C		24	1000	
I_{IB}	Input bias current (see Note 4)	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$		25°C		0.6		pA
				85°C		200	2000	
V_{ICR}	Common-mode input voltage range (see Note 5)			25°C	-0.2 to 4	-0.3 to 4.2		V
				Full range	-0.2 to 3.5			
V_{OH}	High-level output voltage	$V_{ID} = 100\text{ mV}$, $R_L = 10\text{ k}\Omega$		25°C	3.2	3.8		V
				-40°C	3	3.8		
				85°C	3	3.8		
V_{OL}	Low-level output voltage	$V_{ID} = -100\text{ mV}$, $I_{OL} = 0$		25°C		0	50	mV
				-40°C		0	50	
				85°C		0	50	
A_{VD}	Large-signal differential voltage amplification	$V_O = 0.25\text{ V to } 2\text{ V}$, $R_L = 10\text{ k}\Omega$		25°C	5	23		V/mV
				-40°C	3.5	32		
				85°C	3.5	19		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR\text{ min}}$		25°C	65	80		dB
				-40°C	60	81		
				85°C	60	86		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to } 10\text{ V}$, $V_O = 1.4\text{ V}$		25°C	65	95		dB
				-40°C	60	92		
				85°C	60	96		
I_{DD}	Supply current (four amplifiers)	$V_O = 2.5\text{ V}$, No load	$V_{IC} = 2.5\text{ V}$	25°C		2.7	6.4	mA
				-40°C		3.8	8.8	
				85°C		2.1	4.8	
				Full range				

† Full range is -40°C to 85°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.
5. This range also applies to each input individually.

TLC274I, TLC274AI, TLC274BI, TLC279I
LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

electrical characteristics at specified free-air temperature, $V_{DD} = 10\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A^\dagger	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	TLC274I	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	1.1	10	mV
					Full range		13	
		TLC274AI	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	0.9	5	7
					Full range		7	
		TLC274BI	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	390	2000	μV
					Full range		3500	
		TLC279I	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	370	1200	2900
					Full range		2900	
α_{VIO}	Average temperature coefficient of input offset voltage			25°C to 85°C	2			$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current (see Note 4)	$V_O = 5\text{ V},$	$V_{IC} = 5\text{ V}$	25°C	0.1			pA
				85°C	26	1000		
I_{IB}	Input bias current (see Note 4)	$V_O = 5\text{ V},$	$V_{IC} = 5\text{ V}$	25°C	0.7			pA
				85°C	220	2000		
V_{ICR}	Common-mode input voltage range (see Note 5)			25°C	-0.2 to 9	-0.3 to 9.2		V
				Full range	-0.2 to 8.5		V	
V_{OH}	High-level output voltage	$V_{ID} = 100\text{ mV},$	$R_L = 10\text{ k}\Omega$	25°C	8	8.5		V
				-40°C	7.8	8.5		
				85°C	7.8	8.5		
V_{OL}	Low-level output voltage	$V_{ID} = -100\text{ mV},$	$I_{OL} = 0$	25°C	0	50		mV
				-40°C	0	50		
				85°C	0	50		
A_{VD}	Large-signal differential voltage amplification	$V_O = 1\text{ V to }6\text{ V},$	$R_L = 10\text{ k}\Omega$	25°C	10	36		V/mV
				-40°C	7	47		
				85°C	7	31		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}\text{ min}$		25°C	65	85		dB
				-40°C	60	87		
				85°C	60	88		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to }10\text{ V},$	$V_O = 1.4\text{ V}$	25°C	65	95		dB
				-40°C	60	92		
				85°C	60	96		
I_{DD}	Supply current (four amplifiers)	$V_O = 5\text{ V},$ No load	$V_{IC} = 5\text{ V},$	25°C	3.8	8		mA
				-40°C	5.5	10		
				85°C	2.9	6.4		

† Full range is -40°C to 85°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.



TLC274C, TLC274AC, TLC274BC, TLC279C LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A^\dagger	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	TLC274C	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	1.1	10	mV
					Full range		12	
		TLC274AC	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	0.9	5	μV
					Full range		6.5	
TLC274BC	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	340	2000	μV		
			Full range		3000			
TLC279C	$V_O = 1.4\text{ V},$ $R_S = 50\ \Omega,$	$V_{IC} = 0,$ $R_L = 10\text{ k}\Omega$	25°C	320	900	μV		
			Full range		1500			
α_{VIO}	Average temperature coefficient of input offset voltage			25°C to 70°C	1.8		$\mu\text{V}/^\circ\text{C}$	
I_{IO}	Input offset current (see Note 4)	$V_O = 2.5\text{ V},$	$V_{IC} = 2.5\text{ V}$	25°C	0.1		pA	
				70°C	7 300			
I_{IB}	Input bias current (see Note 4)	$V_O = 2.5\text{ V},$	$V_{IC} = 2.5\text{ V}$	25°C	0.6		pA	
				70°C	40 600			
V_{ICR}	Common-mode input voltage range (see Note 5)			25°C	-0.2 to 4	-0.3 to 4.2	V	
				Full range	-0.2 to 3.5		V	
V_{OH}	High-level output voltage	$V_{ID} = 100\text{ mV},$	$R_L = 10\text{ k}\Omega$	25°C	3.2	3.8	V	
				0°C	3	3.8		
				70°C	3	3.8		
V_{OL}	Low-level output voltage	$V_{ID} = -100\text{ mV},$	$I_{OL} = 0$	25°C	0 50		mV	
				0°C	0 50			
				70°C	0 50			
A_{VD}	Large-signal differential voltage amplification	$V_O = 0.25\text{ V to }2\text{ V},$ $R_L = 10\text{ k}\Omega$		25°C	5	23	V/mV	
				0°C	4	27		
				70°C	4	20		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}\text{ min}$		25°C	65	80	dB	
				0°C	60	84		
				70°C	60	85		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to }10\text{ V},$ $V_O = 1.4\text{ V}$		25°C	65	95	dB	
				0°C	60	94		
				70°C	60	96		
I_{DD}	Supply current (four amplifiers)	$V_O = 2.5\text{ V},$ No load	$V_{IC} = 2.5\text{ V},$	25°C	2.7	6.4	mA	
				0°C	3.1	7.2		
				70°C	2.3	5.2		

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.
5. This range also applies to each input individually.

TLC274C, TLC274AC, TLC274BC, TLC279C
LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

electrical characteristics at specified free-air temperature, $V_{DD} = 10\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A^\dagger	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	TLC274C	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	1.1	10	mV
					Full range		12	
		TLC274AC	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	0.9	5	mV
					Full range		6.5	
		TLC274BC	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	390	2000	μV
					Full range		3000	
		TLC279C	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C	370	1200	μV
					Full range		1900	
αV_{IO}	Average temperature coefficient of input offset voltage			25°C to 70°C		2		$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current (see Note 4)	$V_O = 5\text{ V}$	$V_{IC} = 5\text{ V}$	25°C		0.1		pA
				70°C		7	300	
I_{IB}	Input bias current (see Note 4)	$V_O = 5\text{ V}$	$V_{IC} = 5\text{ V}$	25°C		0.7		pA
				70°C		50	600	
V_{ICR}	Common-mode input voltage range (see Note 5)			25°C	-0.2 to 9	-0.3 to 9.2		V
				Full range	-0.2 to 8.5			
V_{OH}	High-level output voltage	$V_{ID} = 100\text{ mV}$	$R_L = 10\text{ k}\Omega$	25°C	8	8.5		V
				0°C	7.8	8.5		
				70°C	7.8	8.4		
V_{OL}	Low-level output voltage	$V_{ID} = -100\text{ mV}$	$I_{OL} = 0$	25°C		0	50	mV
				0°C		0	50	
				70°C		0	50	
A_{VD}	Large-signal differential voltage amplification	$V_O = 1\text{ V to }6\text{ V}$	$R_L = 10\text{ k}\Omega$	25°C	10	36		V/mV
				0°C	7.5	42		
				70°C	7.5	32		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR\text{ min}}$		25°C	65	85		dB
				0°C	60	88		
				70°C	60	88		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to }10\text{ V}$	$V_O = 1.4\text{ V}$	25°C	65	95		dB
				0°C	60	94		
				70°C	60	96		
I_{DD}	Supply current (four amplifiers)	$V_O = 5\text{ V}$, No load	$V_{IC} = 5\text{ V}$	25°C		3.8	8	mA
				0°C		4.5	8.8	
				70°C		3.2	6.8	

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.
 5. This range also applies to each input individually.

TLC274M, TLC279M
LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

operating characteristics, $V_{DD} = 5\text{ V}$

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$R_L = 10\text{ k}\Omega$, $C_L = 20\text{ pF}$, See Figure 1	$V_{IPP} = 1\text{ V}$	25°C		3.6		V/ μ s
				-55°C		4.7		
				125°C		2.3		
			$V_{IPP} = 2.5\text{ V}$	25°C		2.9		
				-55°C		3.7		
				125°C		2		
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, See Figure 2	$R_S = 100\ \Omega$,	25°C		25		nV/ $\sqrt{\text{Hz}}$
B_{OM}	Maximum output swing bandwidth	$V_O = V_{OH}$, $R_L = 10\text{ k}\Omega$, See Figure 1	$C_L = 20\text{ pF}$, See Figure 1	25°C		320		kHz
				-55°C		400		
				125°C		230		
B_1	Unity-gain bandwidth	$V_i = 10\text{ mV}$, See Figure 3	$C_L = 20\text{ pF}$,	25°C		1.7		MHz
				-55°C		2.9		
				125°C		1.1		
ϕ_m	Phase margin	$V_i = 10\text{ mV}$, $C_L = 20\text{ pF}$,	$f = B_1$, See Figure 3	25°C		46°		
				-55°C		49°		
				125°C		41°		

operating characteristics, $V_{DD} = 10\text{ V}$

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$R_L = 10\text{ k}\Omega$, $C_L = 20\text{ pF}$, See Figure 1	$V_{IPP} = 1\text{ V}$	25°C		5.3		V/ μ s
				-55°C		7.1		
				125°C		3.1		
			$V_{IPP} = 5.5\text{ V}$	25°C		4.6		
				-55°C		6.1		
				125°C		2.7		
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, See Figure 2	$R_S = 100\ \Omega$,	25°C		25		nV/ $\sqrt{\text{Hz}}$
B_{OM}	Maximum output swing bandwidth	$V_O = V_{OH}$, $R_L = 10\text{ k}\Omega$, See Figure 1	$C_L = 20\text{ pF}$, See Figure 1	25°C		200		kHz
				-55°C		280		
				125°C		110		
B_1	Unity-gain bandwidth	$V_i = 10\text{ mV}$, See Figure 3	$C_L = 20\text{ pF}$,	25°C		2.2		MHz
				-55°C		3.4		
				125°C		1.6		
ϕ_m	Phase margin	$V_i = 10\text{ mV}$, $C_L = 20\text{ pF}$,	$f = B_1$, See Figure 3	25°C		49°		
				-55°C		52°		
				125°C		44°		

TLC274I, TLC274AI, TLC274BI, TLC279I
LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

operating characteristics, V_{DD} = 5 V

PARAMETER		TEST CONDITIONS		T _A	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	R _L = 10 kΩ, C _L = 20 pF, See Figure 1	V _{I_{PP}} = 1 V	25°C		3.6		V/μs
				-40°C		4.5		
				85°C		2.8		
			V _{I_{PP}} = 2.5 V	25°C		2.9		
				-40°C		3.5		
				85°C		2.3		
V _n	Equivalent input noise voltage	f = 1 kHz, See Figure 2	R _S = 100 Ω,	25°C		25		nV/√Hz
B _{OM}	Maximum output swing bandwidth	V _O = V _{OH} , R _L = 10 kΩ,	C _L = 20 pF, See Figure 1	25°C		320		kHz
				-40°C		380		
				85°C		250		
B ₁	Unity-gain bandwidth	V _i = 10 mV, See Figure 3	C _L = 20 pF,	25°C		1.7		MHz
				-40°C		2.6		
				85°C		1.2		
φ _m	Phase margin	V _i = 10 mV, C _L = 20 pF,	f = B ₁ , See Figure 3	25°C		46°		
				-40°C		49°		
				85°C		43°		

operating characteristics, V_{DD} = 10 V

PARAMETER		TEST CONDITIONS		T _A	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	R _L = 10 kΩ, C _L = 20 pF, See Figure 1	V _{I_{PP}} = 1 V	25°C		5.3		V/μs
				-40°C		6.7		
				85°C		4		
			V _{I_{PP}} = 5.5 V	25°C		4.6		
				-40°C		5.8		
				85°C		3.5		
V _n	Equivalent input noise voltage	f = 1 kHz, See Figure 2	R _S = 100 Ω,	25°C		25		nV/√Hz
B _{OM}	Maximum output swing bandwidth	V _O = V _{OH} , R _L = 10 kΩ,	C _L = 20 pF, See Figure 1	25°C		200		kHz
				-40°C		260		
				85°C		130		
B ₁	Unity-gain bandwidth	V _i = 10 mV, See Figure 3	C _L = 20 pF,	25°C		2.2		MHz
				-40°C		3.1		
				85°C		1.7		
φ _m	Phase margin	V _i = 10 mV, C _L = 20 pF,	f = B ₁ , See Figure 3	25°C		49°		
				-40°C		52°		
				85°C		46°		

TLC274C, TLC274AC, TLC274BC, TLC279C
LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

operating characteristics, $V_{DD} = 5\text{ V}$

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$R_L = 10\text{ k}\Omega$, $C_L = 20\text{ pF}$, See Figure 1	$V_{Ipp} = 1\text{ V}$	25°C		3.6		$V/\mu\text{s}$
				0°C		4		
				70°C		3		
			$V_{Ipp} = 2.5\text{ V}$	25°C		2.9		
				0°C		3.1		
				70°C		2.5		
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, See Figure 2	$R_S = 100\ \Omega$,	25°C		25		$\text{nV}/\sqrt{\text{Hz}}$
BOM	Maximum output swing bandwidth	$V_O = V_{OH}$, $R_L = 10\text{ k}\Omega$,	$C_L = 20\text{ pF}$, See Figure 1	25°C		320		kHz
				0°C		340		
				70°C		260		
B ₁	Unity-gain bandwidth	$V_i = 10\text{ mV}$, See Figure 3	$C_L = 20\text{ pF}$,	25°C		1.7		MHz
				0°C		2		
				70°C		1.3		
ϕ_m	Phase margin	$V_i = 10\text{ mV}$, $C_L = 20\text{ pF}$,	$f = B_1$, See Figure 3	25°C		46°		
				0°C		47°		
				70°C		44°		

operating characteristics, $V_{DD} = 10\text{ V}$

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$R_L = 10\text{ k}\Omega$, $C_L = 20\text{ pF}$, See Figure 1	$V_{Ipp} = 1\text{ V}$	25°C		5.3		$V/\mu\text{s}$
				0°C		5.9		
				70°C		4.3		
			$V_{Ipp} = 5.5\text{ V}$	25°C		4.6		
				0°C		5.1		
				70°C		3.8		
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, See Figure 2	$R_S = 100\ \Omega$,	25°C		25		$\text{nV}/\sqrt{\text{Hz}}$
BOM	Maximum output swing bandwidth	$V_O = V_{OH}$, $R_L = 10\text{ k}\Omega$,	$C_L = 20\text{ pF}$, See Figure 1	25°C		200		kHz
				0°C		220		
				70°C		140		
B ₁	Unity-gain bandwidth	$V_i = 10\text{ mV}$, See Figure 3	$C_L = 20\text{ pF}$,	25°C		2.2		MHz
				0°C		2.5		
				70°C		1.8		
ϕ_m	Phase margin	$V_i = 10\text{ mV}$, $C_L = 20\text{ pF}$,	$f = B_1$, See Figure 3	25°C		49°		
				0°C		50°		
				70°C		46°		

PARAMETER MEASUREMENT INFORMATION

single-supply versus split-supply test circuits

Because the TLC274 and TLC279 are optimized for single-supply operation, circuit configurations used for the various tests often present some inconvenience since the input signal, in many cases, must be offset from ground. This inconvenience can be avoided by testing the device with split supplies and the output load tied to the negative rail. A comparison of single-supply versus split-supply test circuits is shown below. The use of either circuit will give the same result.



FIGURE 1. UNITY-GAIN AMPLIFIER

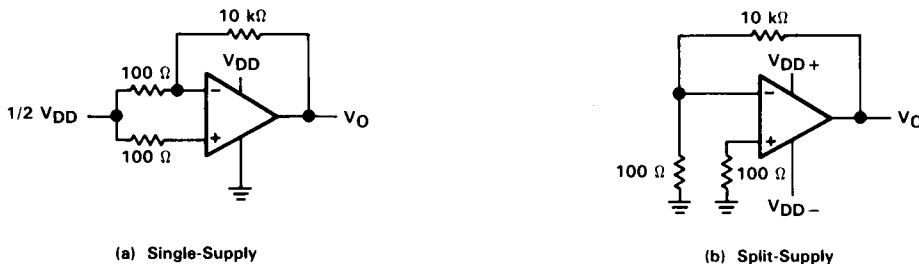


FIGURE 2. NOISE TEST CIRCUIT

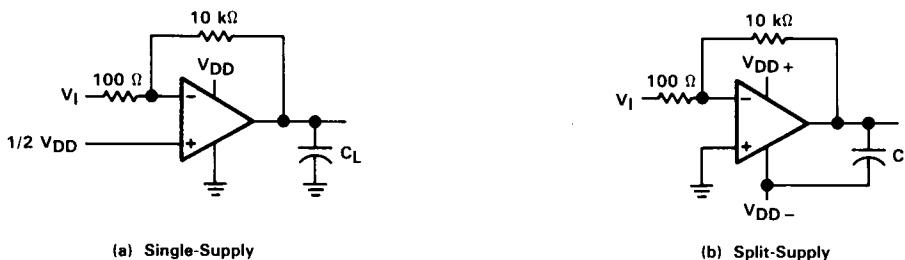


FIGURE 3. GAIN-OF-100 INVERTING AMPLIFIER

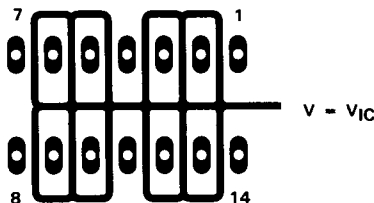
PARAMETER MEASUREMENT INFORMATION

input bias current

Because of the high input impedance of the TLC274 and TLC279 op amps, attempts to measure the input bias current can result in erroneous readings. The bias current at normal room ambient temperature is typically less than 1 pA, a value that is easily exceeded by leakages on the test socket. Two suggestions are offered to avoid erroneous measurements:

1. Isolate the device from other potential leakage sources. Use a grounded shield around and between the device inputs (see Figure 4). Leakages that would otherwise flow to the inputs will be shunted away.
2. Compensate for the leakage of the test socket by actually performing an input bias current test (using a picoammeter) with no device in the test socket. The actual input bias current can then be calculated by subtracting the "open-socket" leakage readings from the readings obtained with a device in the test socket.

One word of caution . . . many automatic testers as well as some bench-top op amp testers use the servo-loop technique with a resistor in series with the device input to measure the input bias current (the voltage drop across the series resistor is measured and the bias current is calculated). This method requires that a device be inserted into the test socket to obtain a correct reading; therefore, an "open-socket" reading is not feasible using this method.



**FIGURE 4. ISOLATION METAL AROUND DEVICE INPUTS
(J AND N DUAL-IN-LINE-PACKAGE)**

low-level output voltage

To obtain low-supply-voltage operation, some compromise was necessary in the input stage. This compromise results in the device low-level output being dependent on both the common-mode input voltage level as well as the differential input voltage level. When attempting to correlate low-level output readings with those quoted in the electrical specifications, these two conditions should be observed. If conditions other than these are to be used, please refer to Figures 14 through 19 in the Typical Characteristics of this data sheet.

input offset voltage temperature coefficient

Erroneous readings often result from attempts to measure temperature coefficient of input offset voltage. This parameter is actually a calculation using input offset voltage measurements obtained at two different temperatures. When one (or both) of the temperatures is below freezing, moisture can collect on both the device and the test socket. This moisture will result in leakage and contact resistance, which can cause erroneous input offset voltage readings. The isolation techniques previously mentioned have no effect on the leakage since the moisture also covers the isolation metal itself, thereby rendering it useless. It is suggested that these measurements be performed at temperatures above freezing to minimize error.

full-power response

Full-power response, the frequency above which the op amp slew rate limits the output voltage swing, is often specified two ways . . . full-linear response and full-peak response. The full-linear response is generally measured by monitoring the distortion level of the output while increasing the frequency of a sinusoidal input signal until the maximum frequency is found above which the output contains significant distortion. The full-peak response is defined as the maximum output frequency, without regard to distortion, above which full peak-to-peak output swing cannot be maintained.

Because there is no industry-wide accepted value for "significant" distortion, the full-peak response is specified in this data sheet and is measured using the circuit of Figure 1. The initial setup involves the use of a sinusoidal input to determine the maximum peak-to-peak output of the device (the amplitude of the sinusoidal wave is increased until clipping occurs). The sinusoidal wave is then replaced with a square wave of the same amplitude. The frequency is then increased until the maximum peak-to-peak output can no longer be maintained (Figure 5). A square wave is used to allow a more accurate determination of the point at which the maximum peak-to-peak output is reached.

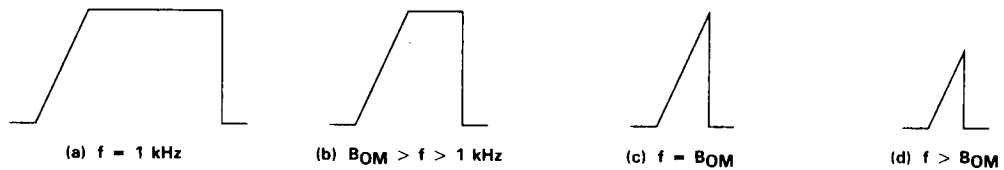


FIGURE 5. FULL-POWER-RESPONSE OUTPUT SIGNAL

test time

Inadequate test time is a frequent problem, especially when testing CMOS devices in a high-volume, short-test-time environment. Internal capacitances are inherently higher in CMOS than in bipolar and BiFET devices and require longer test times than their bipolar and BiFET counterparts. The problem becomes more pronounced with reduced supply levels and lower temperatures.

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLC274
 INPUT OFFSET VOLTAGE

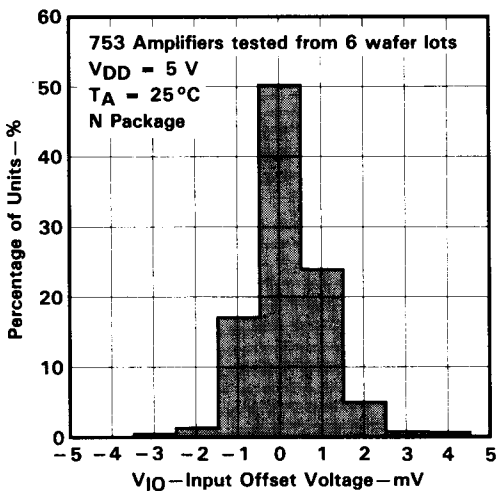


FIGURE 6

DISTRIBUTION OF TLC274
 INPUT OFFSET VOLTAGE

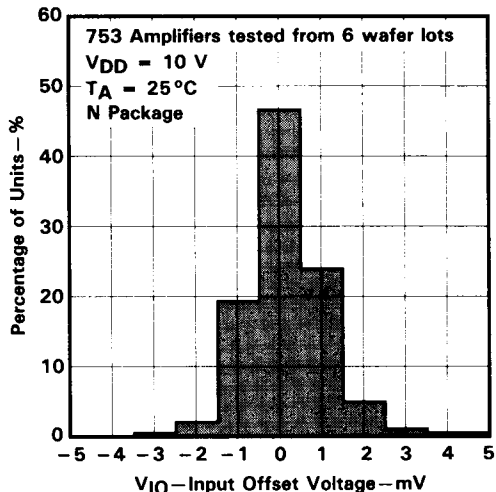


FIGURE 7

DISTRIBUTION OF TLC274 AND TLC279
 INPUT OFFSET VOLTAGE
 TEMPERATURE COEFFICIENT

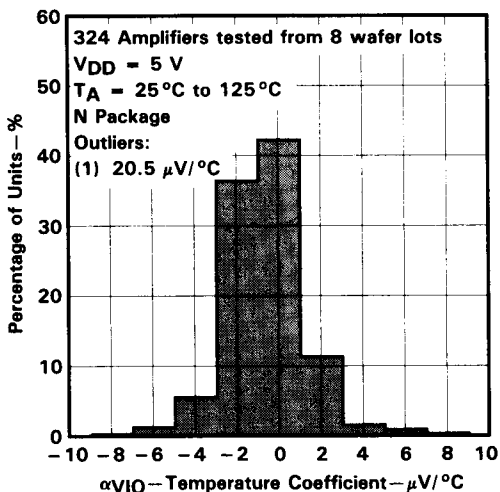


FIGURE 8

DISTRIBUTION OF TLC274 AND TLC279
 INPUT OFFSET VOLTAGE
 TEMPERATURE COEFFICIENT

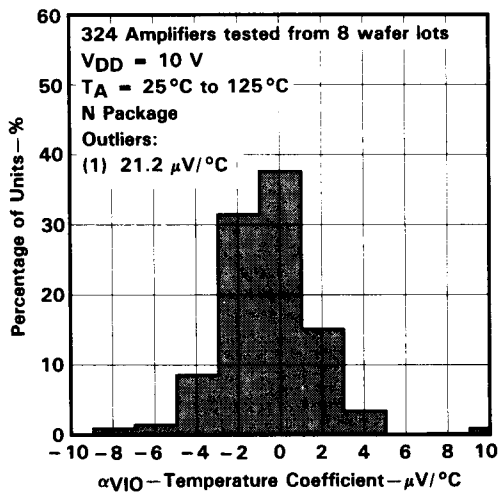


FIGURE 9

TYPICAL CHARACTERISTICS†

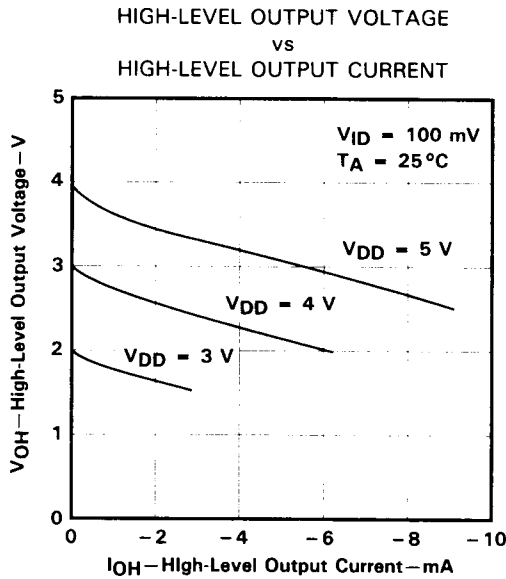


FIGURE 10

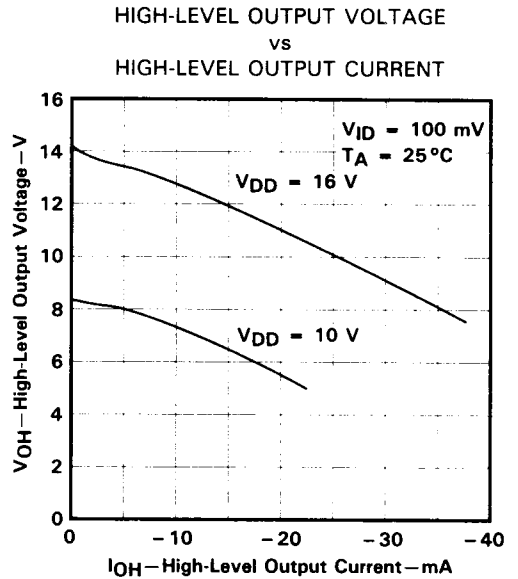


FIGURE 11

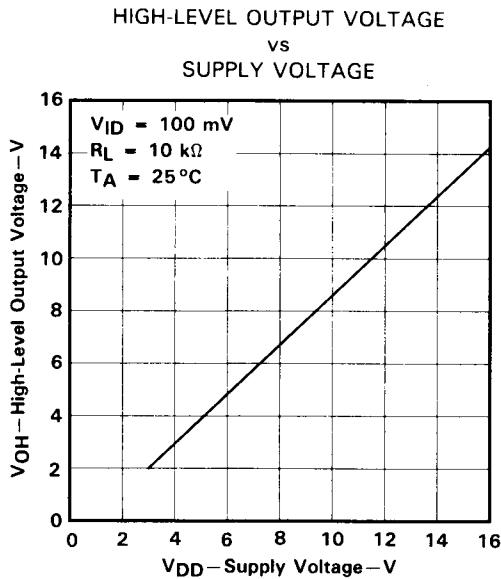


FIGURE 12

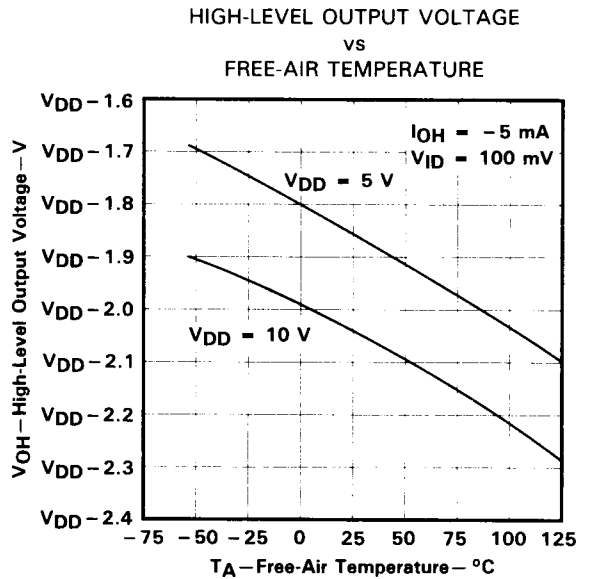


FIGURE 13

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

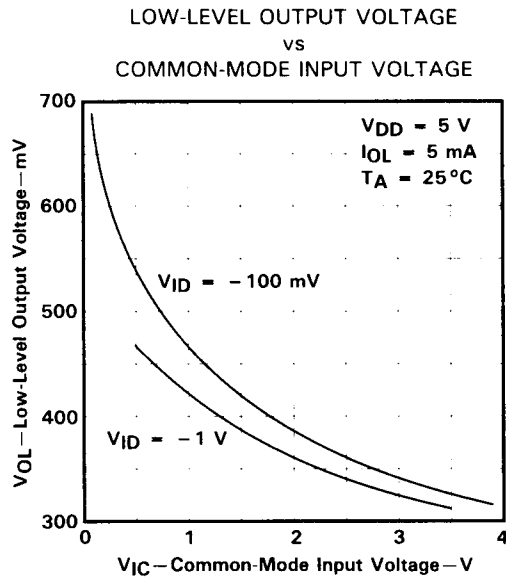


FIGURE 14

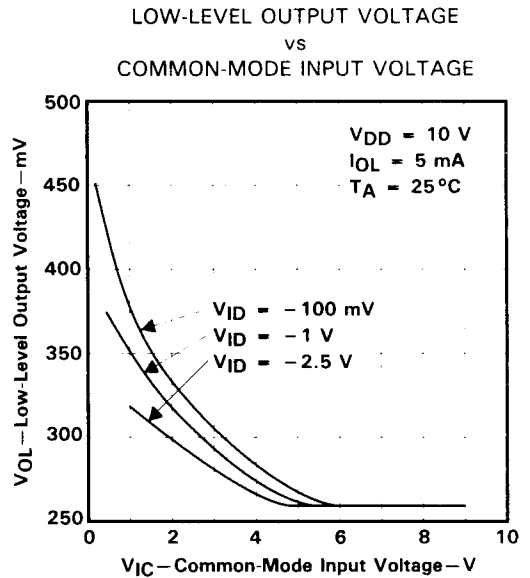


FIGURE 15

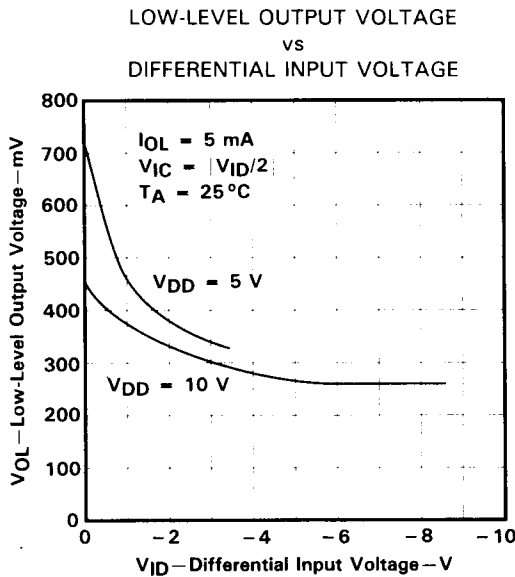


FIGURE 16

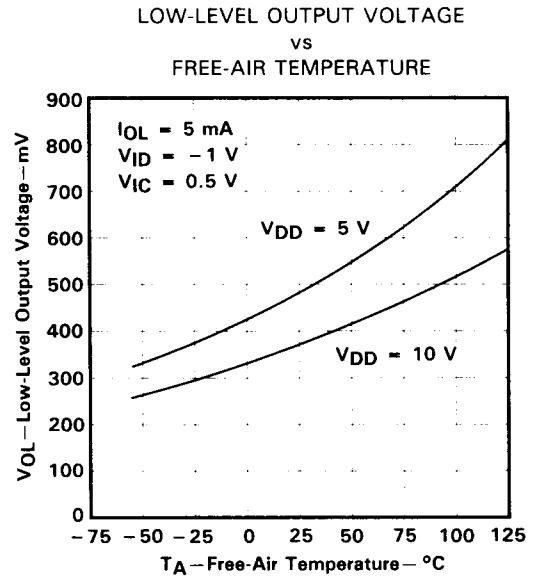


FIGURE 17

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

LOW-LEVEL OUTPUT VOLTAGE
 vs
 LOW-LEVEL OUTPUT CURRENT

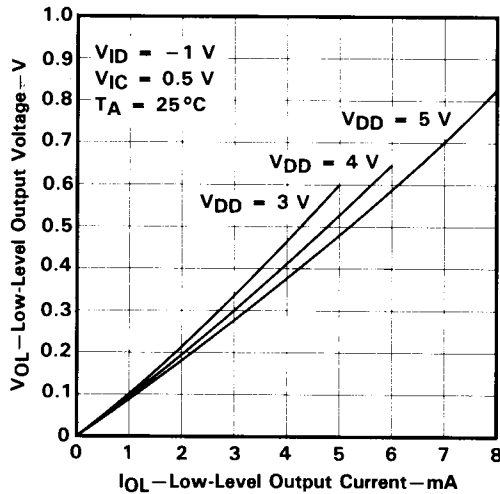


FIGURE 18

LOW-LEVEL OUTPUT VOLTAGE
 vs
 LOW-LEVEL OUTPUT CURRENT

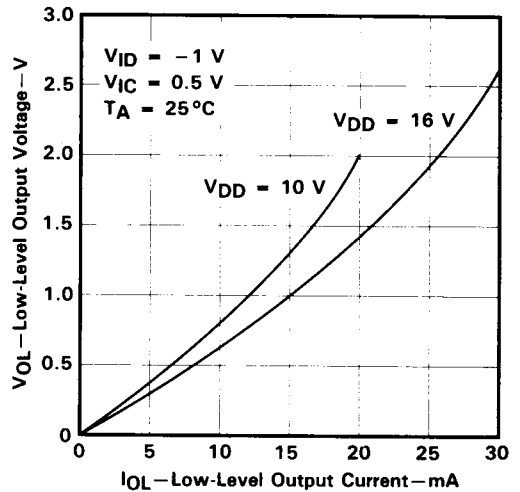


FIGURE 19

LARGE-SIGNAL
 DIFFERENTIAL VOLTAGE AMPLIFICATION
 vs
 SUPPLY VOLTAGE

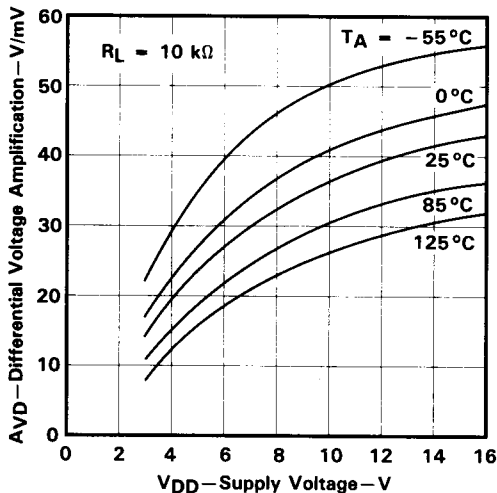


FIGURE 20

LARGE-SIGNAL
 DIFFERENTIAL VOLTAGE AMPLIFICATION
 vs
 FREE-AIR TEMPERATURE

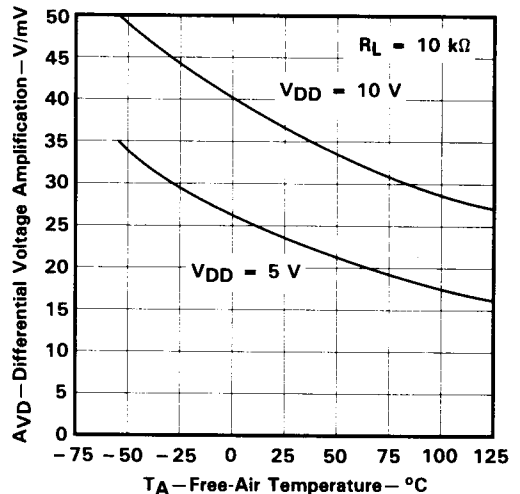


FIGURE 21

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

INPUT BIAS CURRENT AND INPUT OFFSET CURRENT
 vs
 FREE-AIR TEMPERATURE

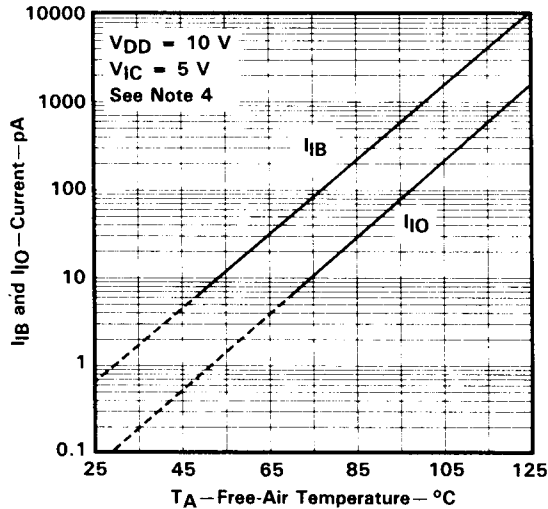


FIGURE 22

COMMON-MODE
 INPUT VOLTAGE POSITIVE LIMIT
 vs
 SUPPLY VOLTAGE

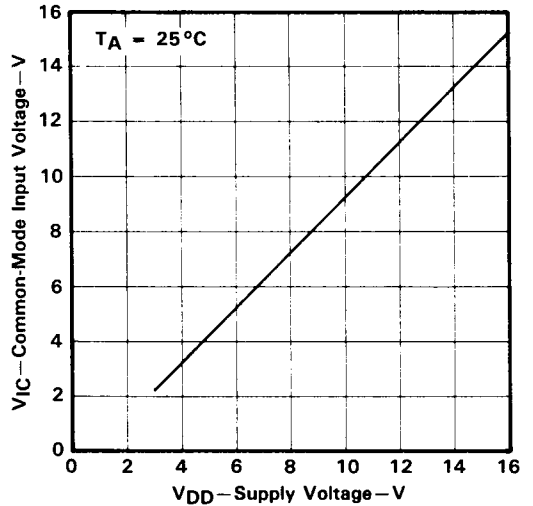


FIGURE 23

SUPPLY CURRENT
 vs
 SUPPLY VOLTAGE

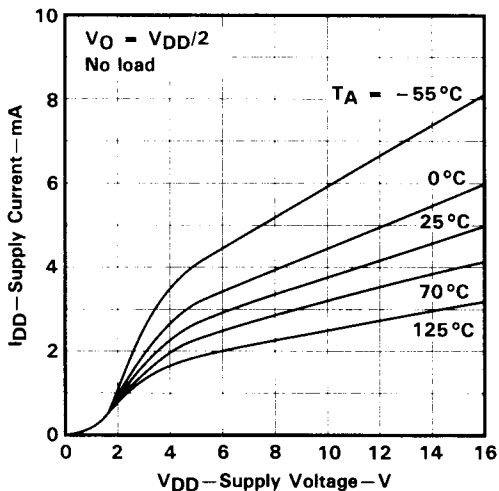


FIGURE 24

SUPPLY CURRENT
 vs
 FREE-AIR TEMPERATURE

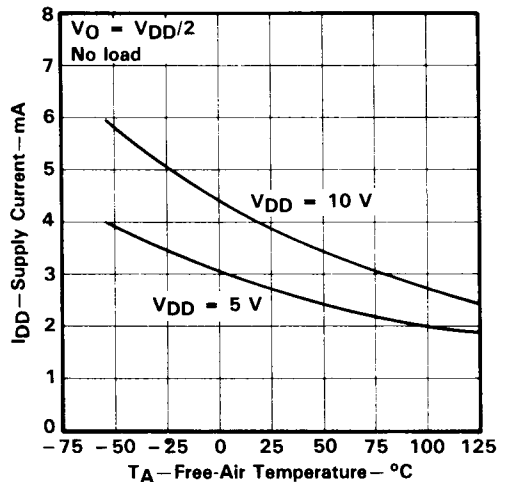


FIGURE 25

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.
 NOTE 4: The typical values of input bias current and input offset current below 5 pA were determined mathematically.

TYPICAL CHARACTERISTICS†

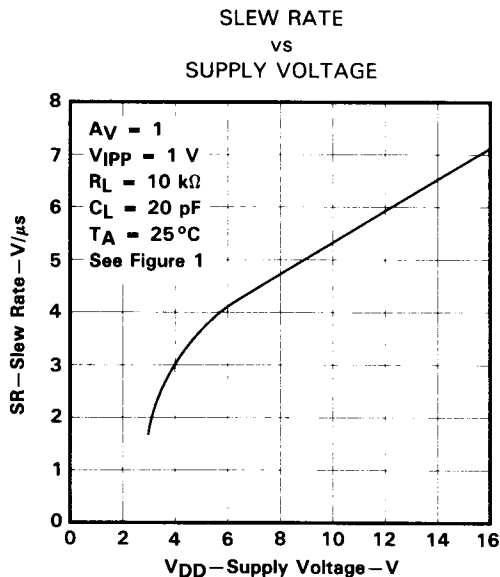


FIGURE 26

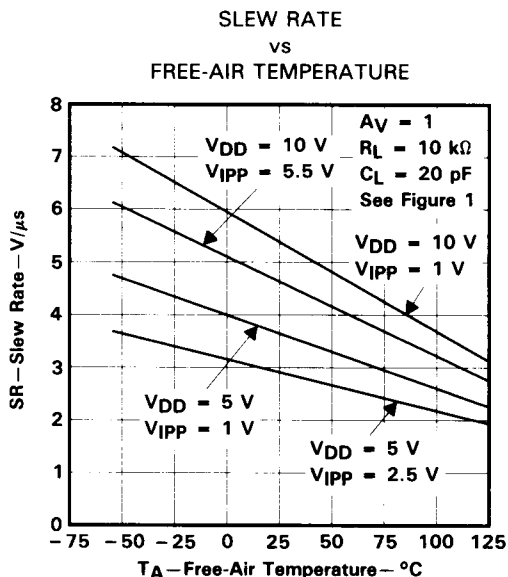


FIGURE 27

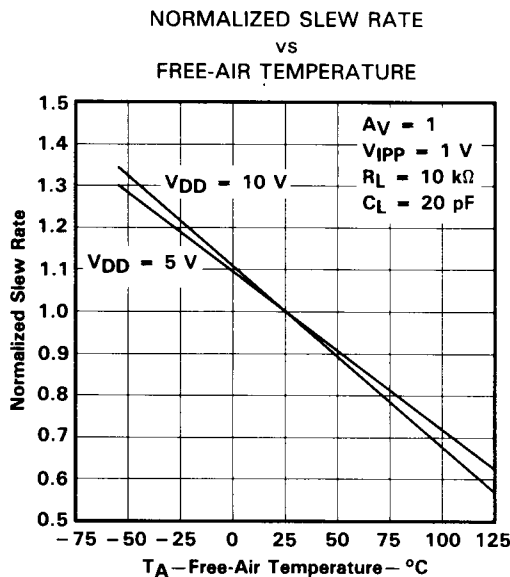


FIGURE 28

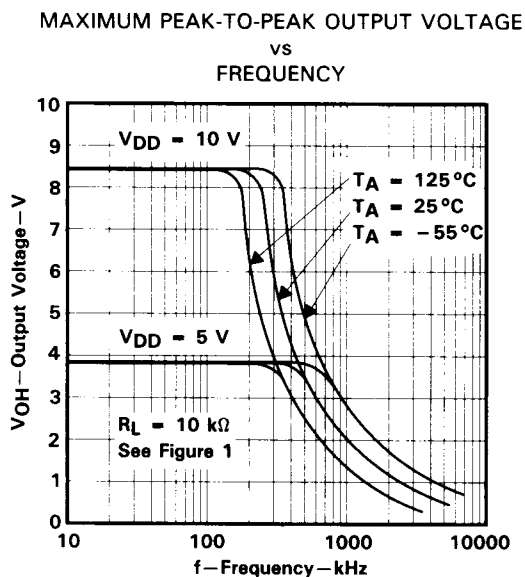


FIGURE 29

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

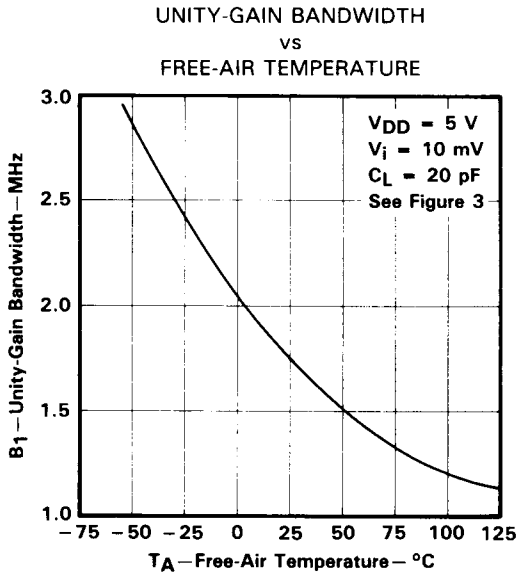


FIGURE 30

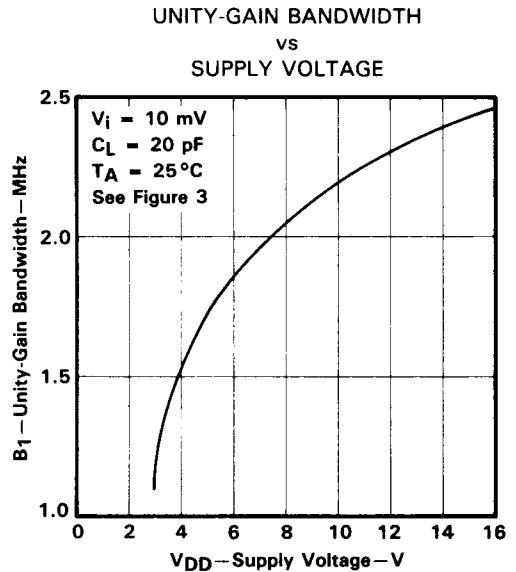


FIGURE 31

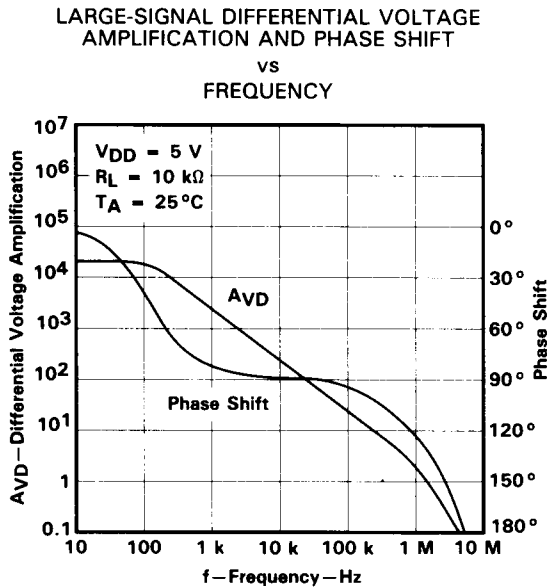


FIGURE 32

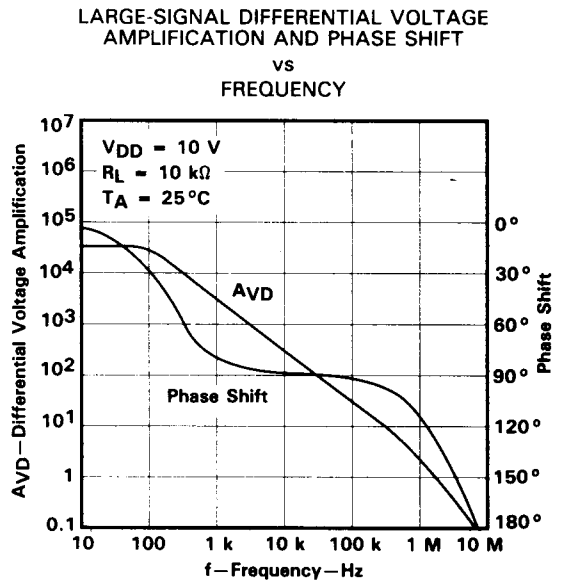


FIGURE 33

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

PHASE MARGIN
 vs
SUPPLY VOLTAGE

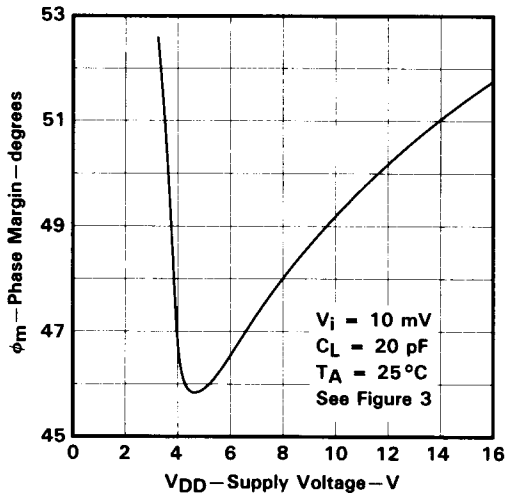


FIGURE 34

PHASE MARGIN
 vs
FREE-AIR TEMPERATURE

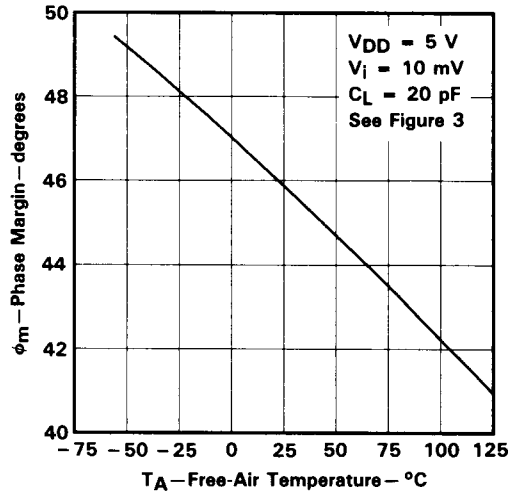


FIGURE 35

PHASE MARGIN
 vs
CAPACITIVE LOAD

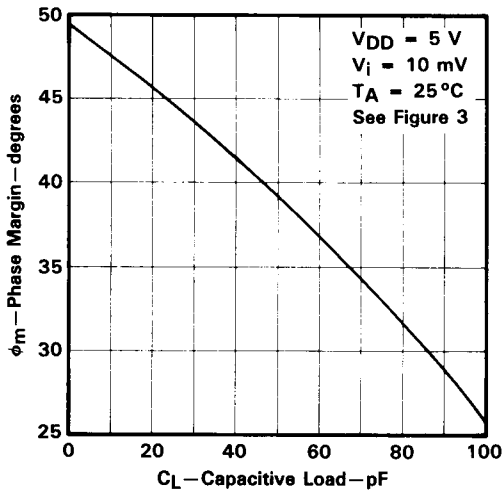


FIGURE 36

EQUIVALENT INPUT NOISE VOLTAGE
 vs
FREQUENCY

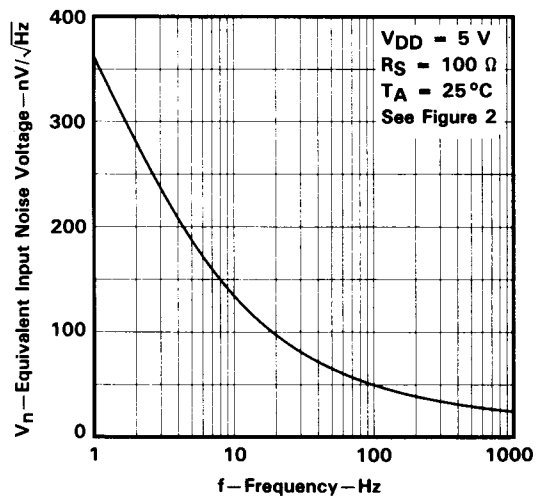


FIGURE 37

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL APPLICATION DATA

single-supply operation

While the TLC274 and TLC279 perform well using dual power supplies (also called balanced or split supplies), the design is optimized for single-supply operation. This design includes an input common-mode voltage range that encompasses ground as well as an output voltage range that pulls down to ground. The supply voltage range extends down to 3 V (C-suffix types), thus allowing operation with supply levels commonly available for TTL and HCMOS; however, for maximum dynamic range, 16-V single-supply operation is recommended.

Many single-supply applications require that a voltage be applied to one input to establish a reference level that is above ground. A resistive voltage divider is usually sufficient to establish this reference level (see Figure 38). The low input bias current of the TLC274 and TLC279 permits the use of very large resistive values to implement the voltage divider, thus minimizing power consumption.

The TLC274 and TLC279 work well in conjunction with digital logic; however, when powering both linear devices and digital logic from the same power supply, the following precautions are recommended:

1. Power the linear devices from separate bypassed supply lines (see Figure 39); otherwise the linear device supply rails can fluctuate due to voltage drops caused by high switching currents in the digital logic.
2. Use proper bypass techniques to reduce the probability of noise-induced errors. Single capacitive decoupling is often adequate; however, high-frequency applications may require RC decoupling.

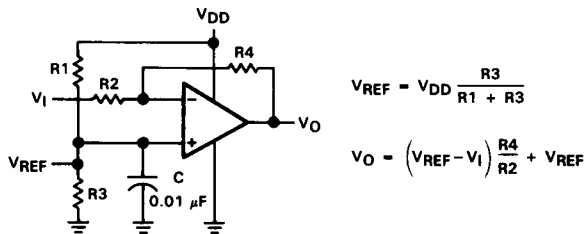


FIGURE 38. INVERTING AMPLIFIER WITH VOLTAGE REFERENCE

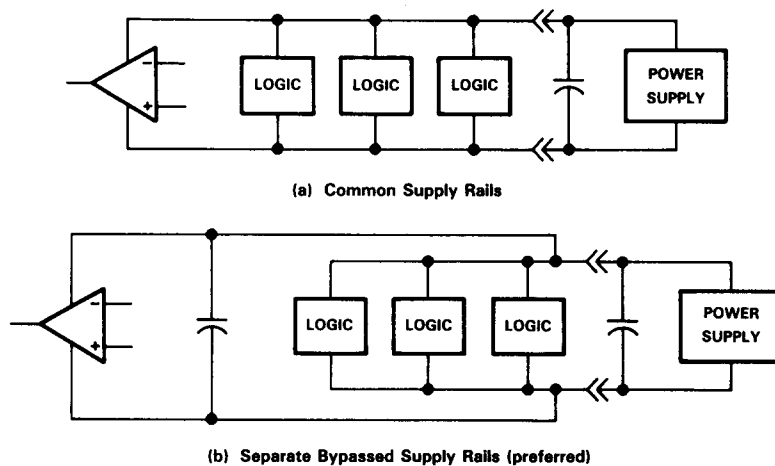


FIGURE 39. COMMON VS SEPARATE SUPPLY RAILS

TYPICAL APPLICATION DATA

input characteristics

The TLC274 and TLC279 are specified with a minimum and a maximum input voltage that, if exceeded at either input, could cause the device to malfunction. Exceeding this specified range is a common problem, especially in single-supply operation. Note that the lower range limit includes the negative rail, while the upper range limit is specified at $V_{DD} - 1$ V at $T_A = 25^\circ\text{C}$ and at $V_{DD} - 1.5$ V at all other temperatures.

The use of the polysilicon-gate process and the careful input circuit design gives the TLC274 and TLC279 very good input offset voltage drift characteristics relative to conventional metal-gate processes. Offset voltage drift in CMOS devices is highly influenced by threshold voltage shifts caused by polarization of the phosphorus dopant implanted in the oxide. Placing the phosphorus dopant in a conductor (such as a polysilicon gate) alleviates the polarization problem, thus reducing threshold voltage shifts by more than an order of magnitude. The offset voltage drift with time has been calculated to be typically $0.1 \mu\text{V}/\text{month}$, including the first month of operation.

Because of the extremely high input impedance and resulting low bias current requirements, the TLC274 and TLC279 are well suited for low-level signal processing; however, leakage currents on printed circuit boards and sockets can easily exceed bias current requirements and cause a degradation in device performance. It is good practice to include guard rings around inputs (similar to those of Figure 4 in the Parameter Measurement Information section). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input (see Figure 40).

The inputs of any unused amplifiers should be tied to ground to avoid possible oscillation.

noise performance

The noise specifications in op amp circuits are greatly dependent on the current in the first-stage differential amplifier. The low input bias current requirements of the TLC274 and TLC279 result in a very low noise current, which is insignificant in most applications. This feature makes the devices especially favorable over bipolar devices when using values of circuit impedance greater than $50 \text{ k}\Omega$, since bipolar devices exhibit greater noise currents.

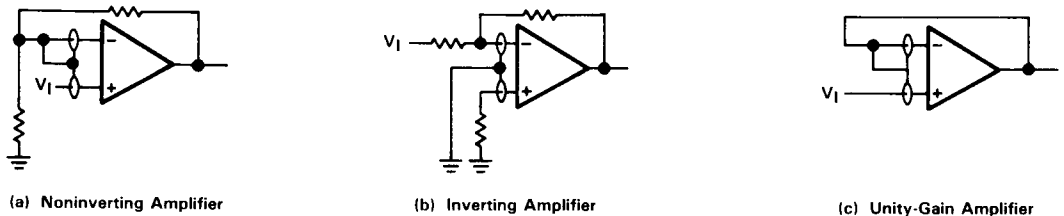


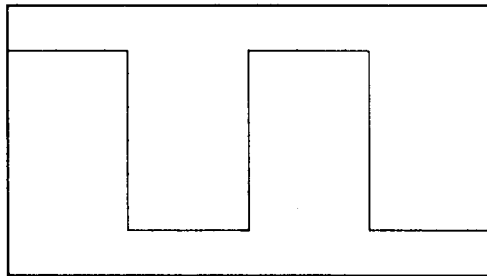
FIGURE 40. GUARD-RING SCHEMES

output characteristics

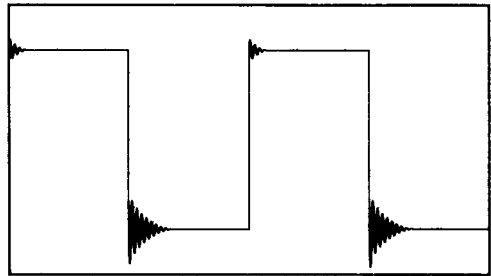
The output stage of the TLC274 and TLC279 is designed to sink and source relatively high amounts of current (see typical characteristics). If the output is subjected to a short-circuit condition, this high current capability can cause device damage under certain conditions. Output current capability increases with supply voltage.

All operating characteristics of the TLC274 and TLC279 were measured using a 20-pF load. The devices will drive higher capacitive loads; however, as output load capacitance increases, the resulting response pole occurs at lower frequencies, thereby causing ringing, peaking, or even oscillation (see Figure 41). In many cases, adding a small amount of resistance in series with the load capacitance will alleviate the problem.

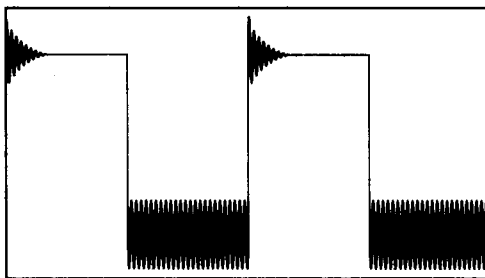
TYPICAL APPLICATION DATA



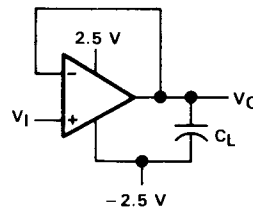
(a) $C_L = 20 \text{ pF}$, $R_L = \text{No load}$



(b) $C_L = 130 \text{ pF}$, $R_L = \text{No load}$



(c) $C_L = 150 \text{ pF}$, $R_L = \text{No load}$



$T_A = 25^\circ\text{C}$
 $f = 1 \text{ kHz}$
 $V_{IPP} = 1 \text{ V}$

(d) Test Circuit

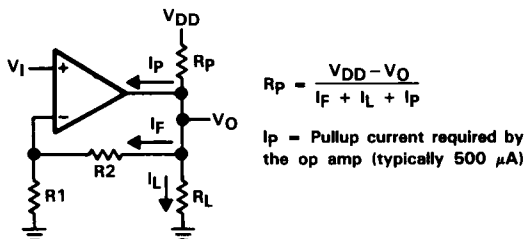
FIGURE 41. EFFECT OF CAPACITIVE LOADS AND TEST CIRCUIT

Although the TLC274 and TLC279 possess excellent high-level output voltage and current capability, methods for boosting this capability are available, if needed. The simplest method involves the use of a pullup resistor (R_p) connected from the output to the positive supply rail (see Figure 42). There are two disadvantages to the use of this circuit. First, the NMOS pulldown transistor N4 (see equivalent schematic) must sink a comparatively large amount of current. In this circuit, N4 behaves like a linear resistor with an on-resistance between approximately 60Ω and 180Ω , depending on how hard the op amp input is driven. With very low values of R_p , a voltage offset from 0 V at the output will occur. Second, pullup resistor R_p acts as a drain load to N4 and the gain of the op amp is reduced at output voltage levels where N5 is not supplying the output current.

feedback

Op amp circuits nearly always employ feedback, and since feedback is the first prerequisite for oscillation, some caution is appropriate. Most oscillation problems result from driving capacitive loads (discussed previously) and ignoring stray input capacitance. A small-value capacitor connected in parallel with the feedback resistor is an effective remedy (see Figure 43). The value of this capacitor is optimized empirically.

TYPICAL APPLICATION DATA



$$R_p = \frac{V_{DD} - V_O}{I_F + I_L + I_P}$$

I_P - Pullup current required by the op amp (typically 500 μ A)

FIGURE 42. RESISTIVE PULLUP TO INCREASE V_{OH}

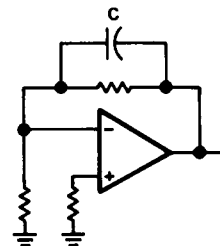


FIGURE 43. COMPENSATION FOR INPUT CAPACITANCE

electrostatic discharge protection

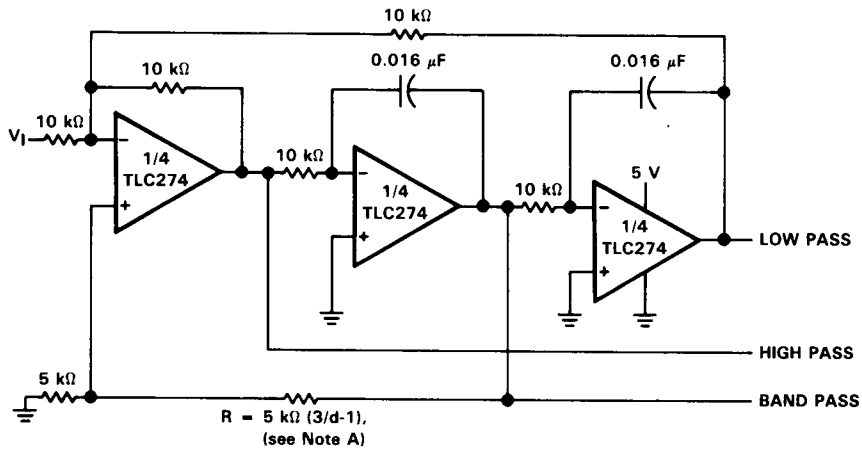
The TLC274 and TLC279 incorporate an internal electrostatic discharge (ESD) protection circuit that prevents functional failures at voltages up to 2000 V as tested under MIL-STD-883C, Method 3015.2. Care should be exercised, however, when handling these devices as exposure to ESD may result in the degradation of the device parametric performance. The protection circuit also causes the input bias currents to be temperature-dependent and have the characteristics of a reverse-biased diode.

latch-up

Because CMOS devices are susceptible to latch-up due to their inherent parasitic thyristors, the TLC274 and TLC279 inputs and outputs were designed to withstand ± 100 -mA surge currents without sustaining latch-up; however, techniques should be used to reduce the chance of latch-up whenever possible. Internal protection diodes should not, by design, be forward biased. Applied input and output voltage should not exceed the supply voltage by more than 300 mV. Care should be exercised when using capacitive coupling on pulse generators. Supply transients should be shunted by the use of decoupling capacitors (0.1 μ F typical) located across the supply rails as close to the device as possible.

The current path established if latch-up occurs is usually between the positive supply rail and ground and can be triggered by surges on the supply lines and/or voltages on either the output or inputs that exceed the supply voltage. Once latch-up occurs, the current flow is limited only by the impedance of the power supply and the forward resistance of the parasitic thyristor and usually results in the destruction of the device. The chance of latch-up occurring increases with increasing temperature and supply voltages.

TYPICAL APPLICATION DATA



NOTES: A. $d =$ damping factor, $1/Q$
 B. Normalized to $10 \text{ k}\Omega$ and $f_c = 1 \text{ kHz}$

FIGURE 44. STATE VARIABLE FILTER

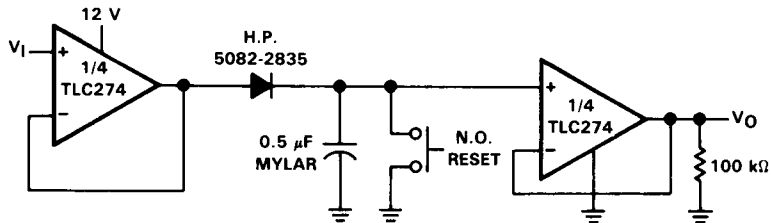
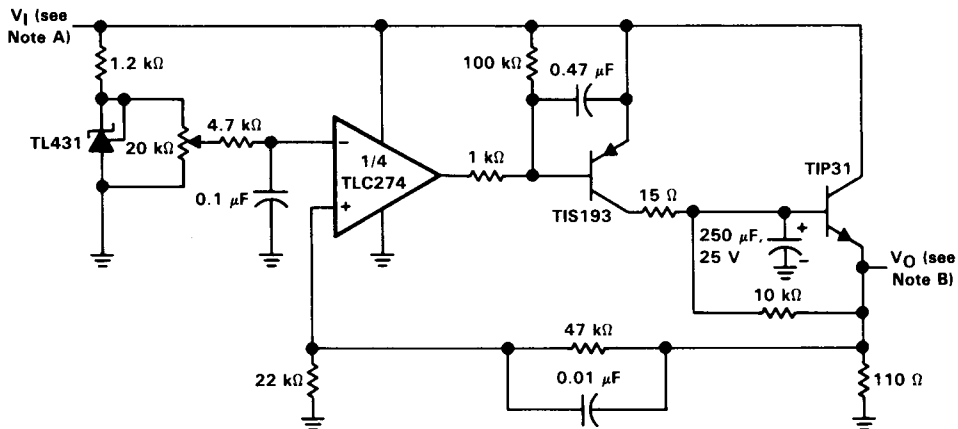


FIGURE 45. POSITIVE-PEAK DETECTOR

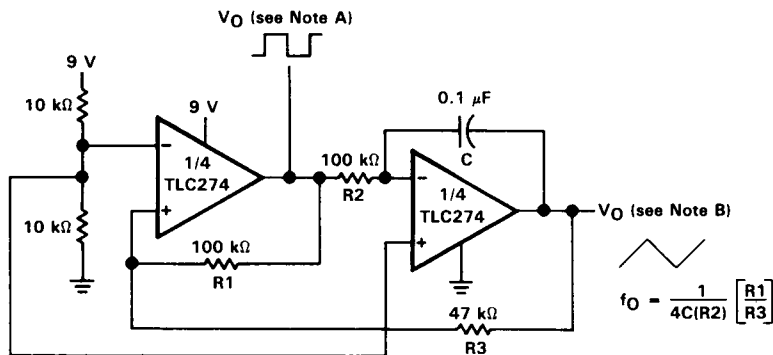
TLC274, TLC274A, TLC274B, TLC279
LinCMOS™ PRECISION QUAD OPERATIONAL AMPLIFIERS

TYPICAL APPLICATION DATA



- NOTES: A. $V_I = 3.5$ to 15 V
 B. $V_O = 2.0$ V, 0 to 1 A

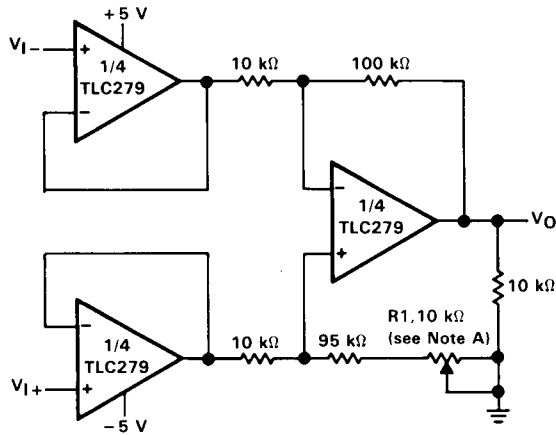
FIGURE 46. LOGIC ARRAY POWER SUPPLY



- NOTES: A. $V_{OPP} = 8$ V
 B. $V_{OPP} = 4$ V

FIGURE 47. SINGLE-SUPPLY FUNCTION GENERATOR

TYPICAL APPLICATION DATA



NOTE A: CMRR adjustment (must be noninductive).

FIGURE 48. LOW-POWER INSTRUMENTATION AMPLIFIER

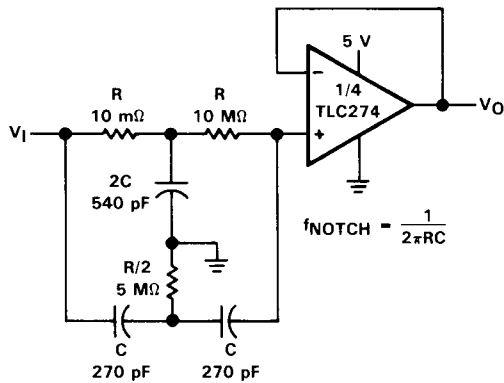


FIGURE 49. SINGLE-SUPPLY TWIN-T NOTCH FILTER